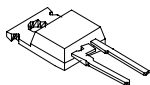
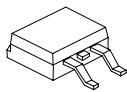


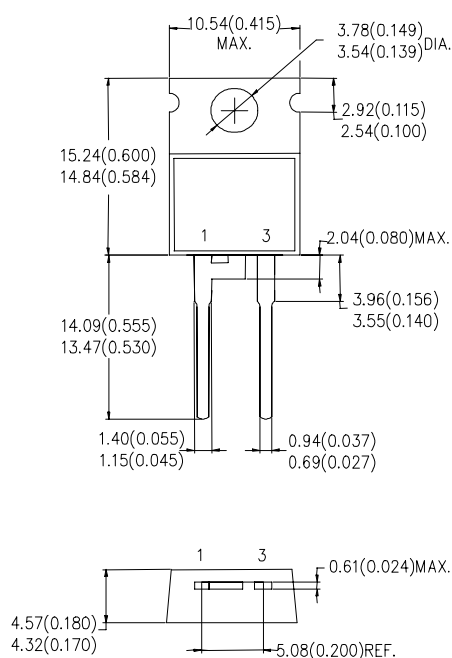
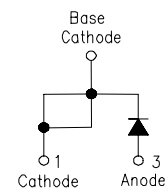
**SENSITRON****SEMICONDUCTOR****6TQ...  
6TQ...S****TECHNICAL DATA  
DATA SHEET****6TQ.../6TQ...S SCHOTTKY RECTIFIER****Applications:**

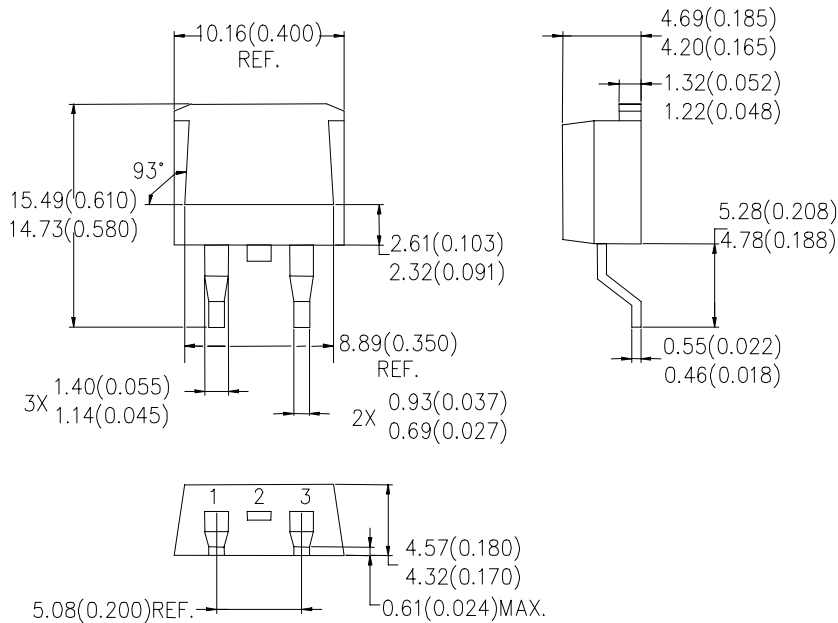
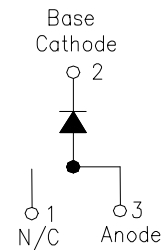
- Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

**Features:**

- 175° C T<sub>J</sub> operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

Case Styles	
<b>6TQ...</b>  <b>TO-220</b>	<b>6TQ...S</b>  <b>D²PAK</b>

**Mechanical Dimensions: In Inches / mm****TO-220AC**

**SENSITRON****SEMICONDUCTOR****6TQ...  
6TQ...S****D<sup>2</sup>PAK****Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	35(6TQ035) 40(6TQ040) 45(6TQ045)	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_C = 164^\circ\text{C}$ , rectangular wave form	6	A
Max. Peak One Cycle Non-Repetitive Surge Current	$I_{FSM}$	8.3 ms, half Sine pulse	160	A
Non-Repetitive Avalanche Energy	$E_{AS}$	$T_J = 25^\circ\text{C}$ , $I_{AS} = 1.20\text{ A}$ , $L = 11.10\text{mH}$	8	mJ
Repetitive Avalanche Current	$I_{AR}$	Current decaying linearly to zero in 1 $\mu\text{sec}$ Frequency limited by $T_J$ max. $V_A = 1.5 \times V_R$ typical	1.2	A

**Electrical Characteristics:**

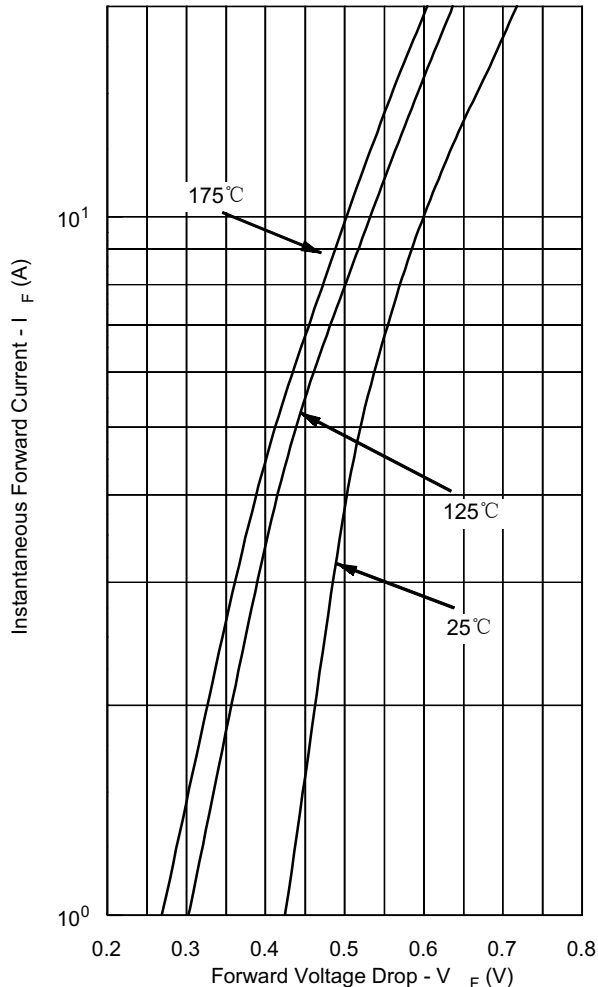
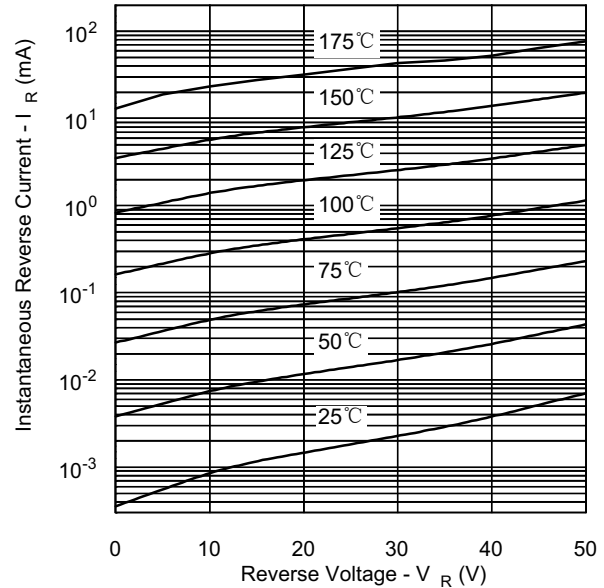
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 6 A, Pulse, $T_J = 25^\circ\text{C}$	0.60	V
	$V_{F2}$	@ 12 A, Pulse, $T_J = 25^\circ\text{C}$	0.73	V
		@ 6 A, Pulse, $T_J = 125^\circ\text{C}$	0.53	V
		@ 12 A, Pulse, $T_J = 125^\circ\text{C}$	0.64	V
Max. Reverse Current	$I_{R1}$	@ $V_R = \text{Rated } V_R$ , Pulse, $T_J = 25^\circ\text{C}$	0.8	mA
	$I_{R2}$	@ $V_R = \text{Rated } V_R$ , Pulse, $T_J = 125^\circ\text{C}$	7	mA
Max. Junction Capacitance	$C_T$	@ $V_R = 5\text{V}$ , $T_C = 25^\circ\text{C}$ $f_{SIG} = 1\text{MHz}$	400	pF
Typical Series Inductance	$L_S$	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	$dv/dt$	-	10,000	V/ $\mu\text{s}$

**SENSITRON****SEMICONDUCTOR****6TQ...****6TQ...S**

\* Pulse Width &lt; 300μs, Duty Cycle &lt; 2%

**Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	$T_J$	-	-55 to +175	°C
Max. Storage Temperature	$T_{stg}$	-	-55 to +175	°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	2.2	°C/W
Typical Thermal Resistance, Case to Heat Sink	$R_{\theta CS}$	Mounting surface, smooth and greased	0.50	°C/W
Approximate Weight	wt	-	2	g
Mounting Torque	$T_M$	-	6 (min) 12 (max)	Kg-cm
Case Style	TO-220 D <sup>2</sup> PAK (Suffix "s" for D <sup>2</sup> PAK; "MBRB xxxx" for D <sup>2</sup> PAK)			

**Typical Forward Characteristics****Typical Reverse Characteristics****Typical Junction Capacitance**